Application Serial No. 10/583,018
Reply to Non-Final Office Action of April 29, 2008

PATENT Docket: CU-4878

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Amendments to the Abstract

Please <u>replace</u> the Abstract with the following amended Abstract:

SEP 2 3 2008

The object of the invention is to provide a A highly reliable organic functional element such as an organic EL element or an organic semiconductor element exemplified by an organic TFT element which that can be manufactured without requiring a vapor deposition process for forming an electrode on an organic material layer. Consequently, such Such an organic functional element can be large-sized easily and produced at lower cost. In addition, no damage is caused to the organic material layer during formation of the electrode, and the organic functional element is not affected by environmental changes. Additionally, there is no damage to the organic material layer during its formation and it is not affected by environmental changes. Also disclosed is a method for manufacturing such an organic functional element. To attain the above-mentioned objective, the present invention provides and The organic functional element comprising includes at least a plurality of electrodes and an organic material layer which is characterized in that at. At least one of the electrodes is composed of a metal having a melting point not higher than a temperature that is higher by 30°C than the glass transition temperature of the organic material layer no higher than 30°C above the glass transition temperature of the organic material layer.